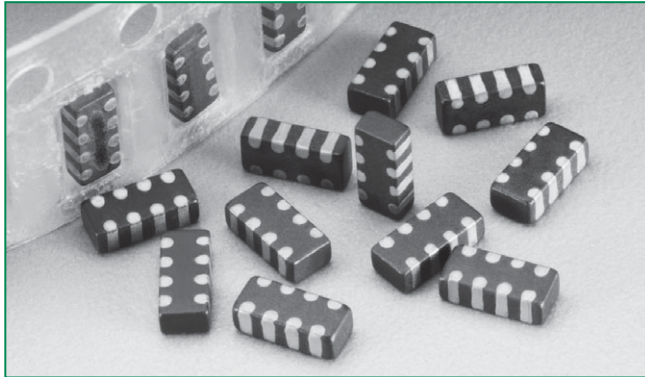


RoHS **MLN SurgeArray™ Suppressor**



Size Table

Metric	EIA
3216	1206

Applications

- Data, Diagnostic I/O Ports
- Analog Signal/Sensor Lines
- Portable/Hand-Held Products
- Mobile
- Communications/Cellular Phones
- Computer/DSP Products
- Industrial Instruments Including Medical

Description

The MLN SurgeArray™ Suppressor is designed to help protect components from transient voltages that exist at the circuit board level. This device provides four independent suppressors in a single leadless chip in order to reduce part count and placement time as well as save space on printed circuit boards.

SurgeArray™ devices are intended to suppress ESD, EFT and other transients in order to protect integrated circuits or other sensitive components operating at any voltage up to 18V_{DC}. SurgeArray™ devices are rated to the IEC 61000-4-2 human body model ESD to help products attain EMC compliance. The array offers excellent isolation and low crosstalk between sections.

The inherent capacitance of the SurgeArray™ Suppressor permits it to function as a filter/suppressor, thereby replacing separate Zener/capacitor combinations.

The MLN array is manufactured using the Littelfuse Multilayer technology process and is similar to the Littelfuse ML and MLE Series of discrete leadless chips.

Features

- RoHS Compliant
- Four individual devices in one chip
- ESD rated to IEC 61000-4-2 (Level 4)
- AC characterized for impedance and capacitance
- Low adjacent channel crosstalk, -55dB at 10MHz (Typ)
- Low leakage
- Operating voltage up to 18V_(MDC)
- -55°C to 125°C operating temp range
- Low-profile, PCMCIA compatible

Absolute Maximum Ratings

• For ratings of individual members of a series, see device ratings and specifications table.

Continuous	MLN Series	Units
Steady State Applied Voltage:		
DC Voltage Range (V _{MDC})	5.5 - 18	V
Operating Ambient Temperature Range (T _A)	-55 to +125	°C
Storage Temperature Range (T _{STG})	-55 to +150	°C

Device Ratings and Specifications Any Single Section

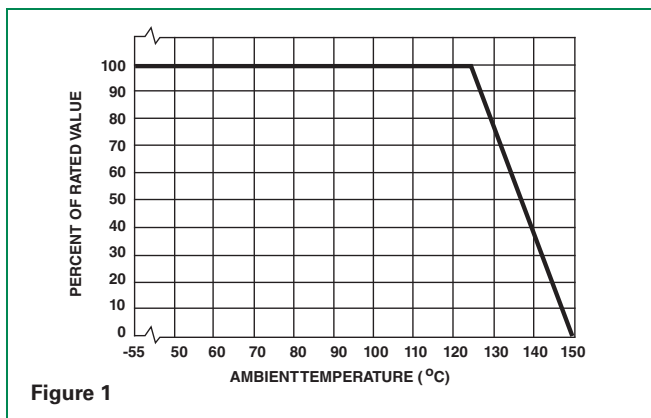
Part Number	Maximum Ratings (125°C)			Specifications (25°C)							
	Maximum Continuous Working Voltage	Maximum Non-repetitive Surge Current (8/20 μ s)	Maximum Non-repetitive Surge Energy (10/1000 μ s)	Maximum Clamping Voltage (at Noted 8/20 μ s Current)	Typical ESD Suppression Voltage (Note1)			Nominal Voltage at 1mA DC Test Current		Capacitance at 1 MHz (1V p-p)	
	$V_{M(DC)}$	I_{TM}	W_{TM}	V_C	(Note 2) 8kV Contact		(Note 3) 15kV Air	$V_{N(DC)}$ Min	$V_{N(DC)}$ Max	(Note 4) C	
					Peak	Clamp	Peak			TYP	MAX
(V)	(A)	(J)	(V)	(V)	(V)	(V)	(V)	(V)	(pF)	(pF)	
V5.5MLN41206	5.5	30	0.10	15.5 at 2A	60	35	45	7.10	10.8	430	520
V9MLN41206	9.0	30	0.10	23.0 at 2A	95	50	75	11.0	16.0	250	300
V14MLN41206	14.0	30	0.10	30.0 at 2A	110	55	85	15.9	20.3	140	175
V18MLN41206	18.0	30	0.10	40.0 at 2A	165	63	100	22.0	28.0	100	125
V18MLN41206L	18.0	30	0.05	50.0 at 1A	200	95	130	25.0	35.0	45	75

NOTES:

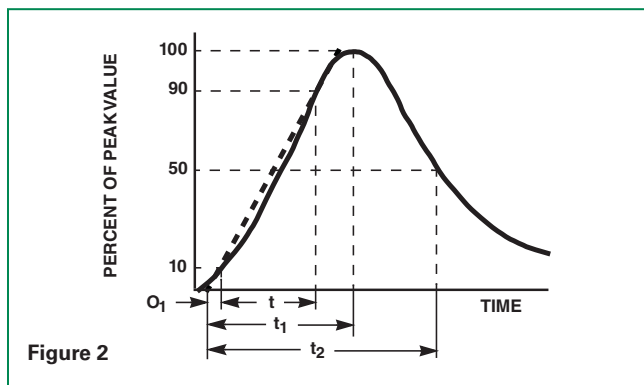
- Tested to IEC61000-4-2 Human Body Model (HBM) discharge test circuit.
- Direct discharge to device terminals (IEC preferred test method).
- Corona discharge through air (represents actual ESD event)
- Capacitance may be customized, contact Sales.

Peak Current and Energy Derating Curve

For applications exceeding 125°C ambient temperature, the peak surge current and energy ratings must be reduced.



Peak Pulse Current Test Waveform for Clamping Voltage

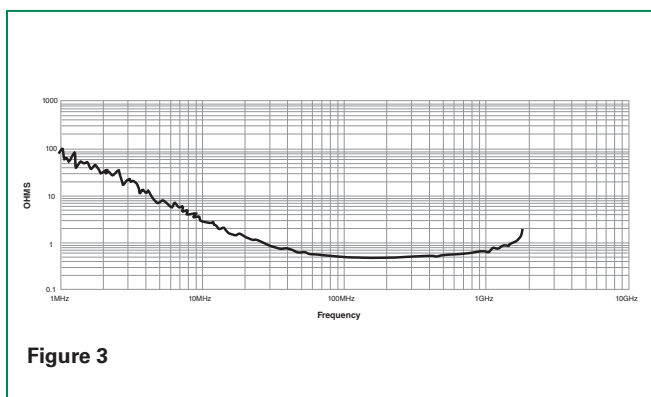


O_1 = Virtual Origin of Wave
 T = Time from 10% to 90% of Peak
 T_1 = Rise Time = $1.25 \times T$
 T_2 = Decay Time (Impulse Duration)

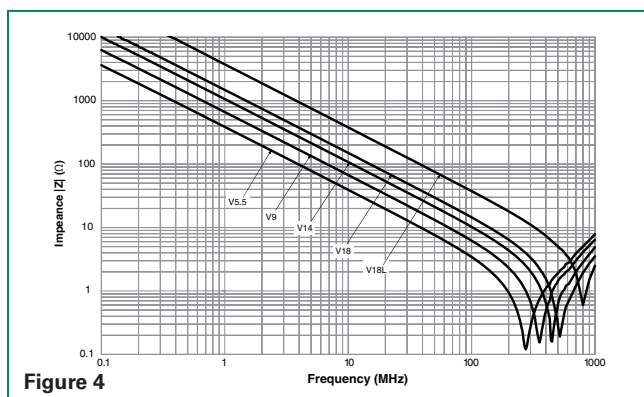
Example:
 For an 8/20 μ s Current Waveform:
 $8\mu s = T_1 =$ Rise Time
 $20\mu s = T_2 =$ Virtual Time to Half Value

Typical Performance Curves

Equivalent Series Resistance



Impedance vs Frequency, 1206 Size



Typical Performance Curves (continued)

Nominal Voltage Stability to IEC 1000-4-2 (8kV Contact Method, One Section)

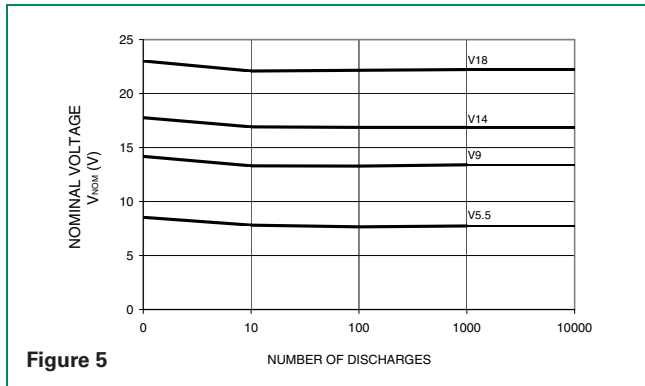


Figure 5

1206 Size Pulse Rating for Long Duration Surges (Any Single Section)

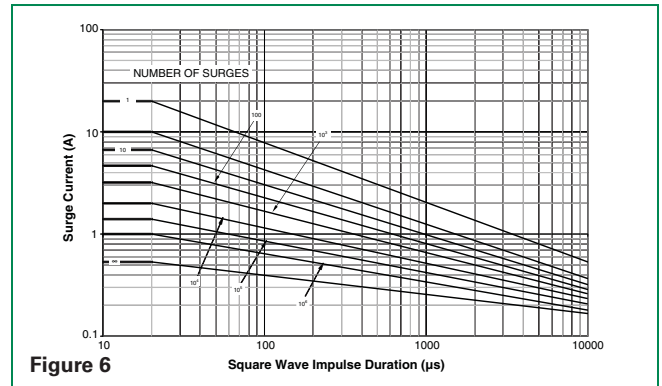


Figure 6

V-I Characteristic, 1206 size

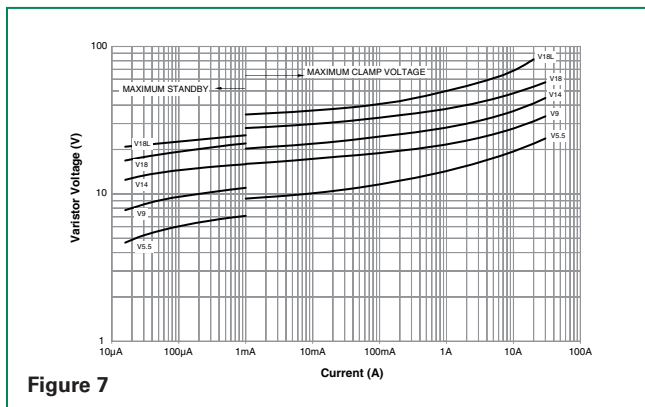


Figure 7

Capacitance vs Frequency, 1206 Size

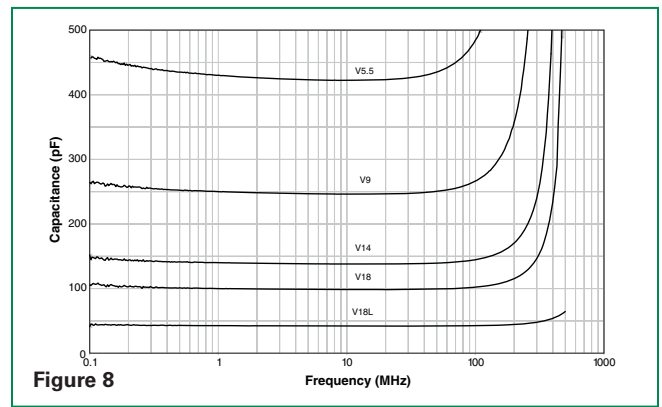


Figure 8

Adjacent Channel Crosstalk

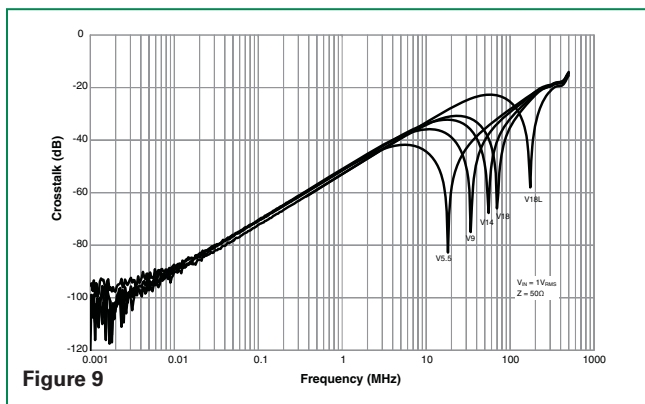


Figure 9

Lead (Pb) Soldering Recommendations

The principal techniques used for the soldering of components in surface mount technology are IR Re-flow and Wave soldering. Typical profiles are shown on the right.

The recommended solder for the MLN suppressor is a 62/36/2 (Sn/Pb/Ag), 60/40 (Sn/Pb) or 63/37 (Sn/Pb). Littelfuse also recommends an RMA solder flux.

Wave soldering is the most strenuous of the processes. To avoid the possibility of generating stresses due to thermal shock, a preheat stage in the soldering process is recommended, and the peak temperature of the solder process should be rigidly controlled.

When using a reflow process, care should be taken to ensure that the MLN chip is not subjected to a thermal gradient steeper than 4 degrees per second; the ideal gradient being 2 degrees per second. During the soldering process, preheating to within 100 degrees of the solder's peak temperature is essential to minimize thermal shock.

Once the soldering process has been completed, it is still necessary to ensure that any further thermal shocks are avoided. One possible cause of thermal shock is hot printed circuit boards being removed from the solder process and subjected to cleaning solvents at room temperature. The boards must be allowed to cool gradually to less than 50°C before cleaning.

Reflow Solder Profile

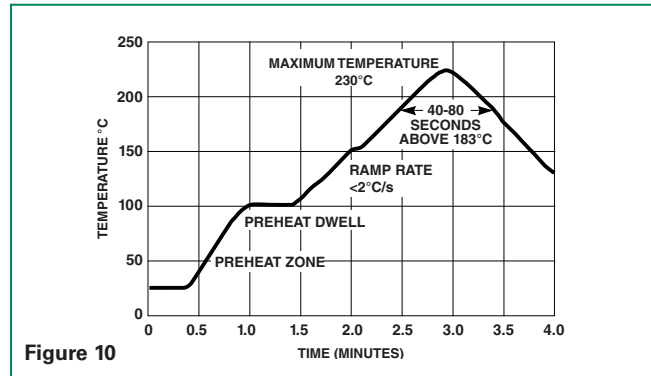


Figure 10

Wave Solder Profile

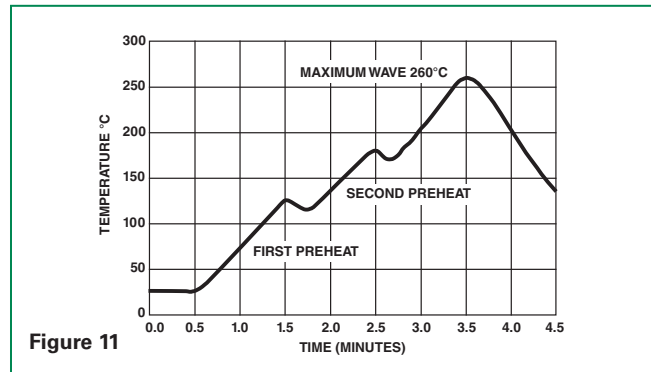
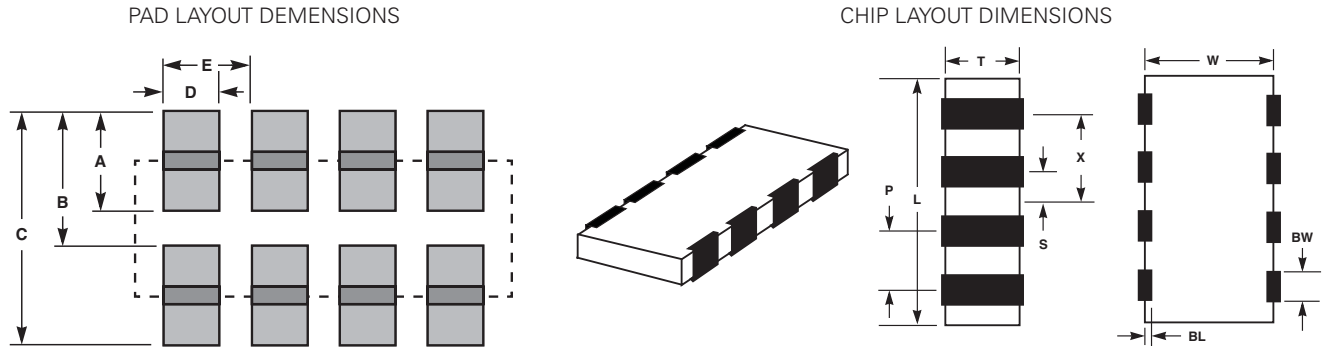


Figure 11

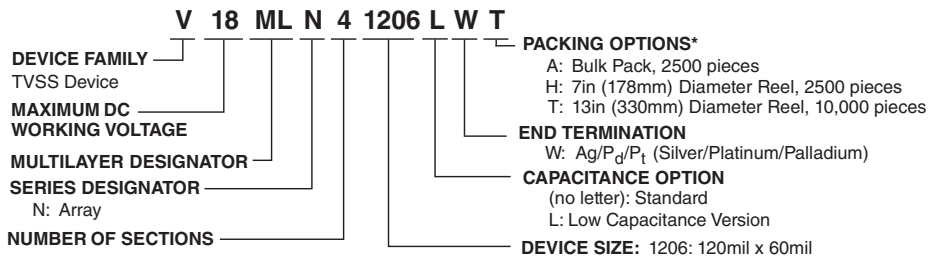
Product Dimensions (mm)



Dimension	1206 Size	
	IN	MM
A	0.890	0.035
B	1.650	0.065
C	2.540	0.100
D	0.460	0.018
E	0.790	0.030
L	0.126 \pm 0.008	3.200 \pm 0.200
W	0.063 \pm 0.008	1.600 \pm 0.200
T	0.053 Max	1.350 Max
BW	0.016 \pm 0.004	0.410 \pm 0.100
BL	0.007 +0.01/- 0.002	0.180 +0.25/-0.050
P	0.030 Ref	0.760 Ref
X	0.045 \pm 0.004	1.140 \pm 0.100
S	0.015 \pm 0.004	0.380 \pm 0.100

MLN Series

Part Numbering System

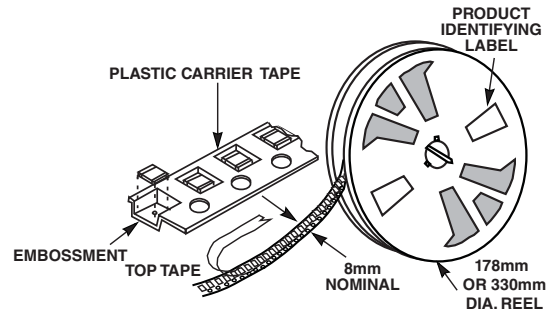
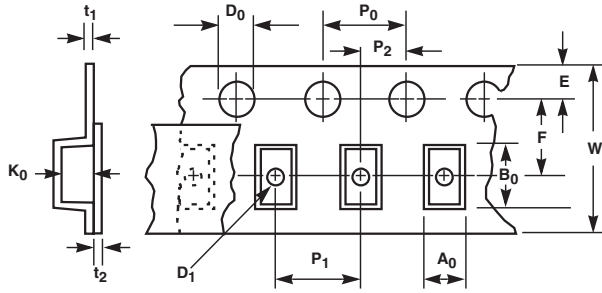


Packaging*

Device Size	Quantity		
	13" Inch Reel ("T" Option)	7" Inch Reel ("H" Option)	Bulk Pack ("A" Option)
1206	10,000	2,500	2,500

*(Packaging) It is recommended that parts be kept in the sealed bag provided and that parts be used as soon as possible when removed from bags.

Tape and Reel Specifications



Symbol	Description	Dimensions in Millimeters
A_0	Width of Cavity	Dependent on Chip Size to Minimize Rotation.
B_0	Length of Cavity	Dependent on Chip Size to Minimize Rotation.
K_0	Depth of Cavity	Dependent on Chip Size to Minimize Rotation.
W	Width of Tape	8 -/+0.2
F	Distance Between Drive Hole Centers and Cavity Centers	3.5 -/+0.5
E	Distance Between Drive Hole Centers and Tape Edge	1.75 -/+0.1
P_1	Distance Between Cavity Center	4 -/+0.1
P_2	Axial Distance Between Drive Hole Centers and Cavity Centers	2 -/+0.1
P_0	Axial Distance Between Drive Hole Centers	4 -/+0.1
D_0	Drive Hole Diameter	1.55 -/+0.05
D_1	Diameter of Cavity Piercing	1.05 -/+0.05
T_1	Embossed Tape Thickness	0.3 Max
T_2	Top Tape Thickness	0.1 Max

Notes :

- Conforms to EIA-481-1, Revision A
- Can be supplied to IEC publication 286-3